### 1. General Description

The WR1005 series are CMOS-based low-dropout, low-power linear regulators, offering 1A with low dropout voltage, high ripple rejection, high output accuracy and low supply current. The WR1005 series consist of an accurate voltage-reference block, an error amplifier, a voltage-setting resistor net, a PMOSFET pass device, a thermal-shutdown circuit, and a current limit circuit with short protection.

The WR1005 series use a type of outstanding CMOS process to minimize the supply current. A low on-resistance PMOS pass device is equipped for lower dropout voltage. WR1005 also possess the EN function to save more energy and extend the battery life.

The WR1005 series are available in the DFN16×12-8 package.

### 2. Features

- Wide Input Voltage Range: 2.5V to 5.5V
- Output Current: 1A
- Output Voltage Range: 1.0V to 3.3V
- Very Low I<sub>Q</sub>: 160μA
- Excellent Load/Line Transient Response
- Line Regulation: 0.02% typical
- Built-in over current protection and thermal shutdown circuit
- Built-in Start from EN Current Suppression
   Circuit and Current Limit
- Reverse Current Protection
- Built-in Auto-discharging circuit (optional)

### 3. Applications

- Cellphones, radiophone, digital cameras
- Bluetooth, wireless handsets
- Others portable electronic device

# 4. Typical Application

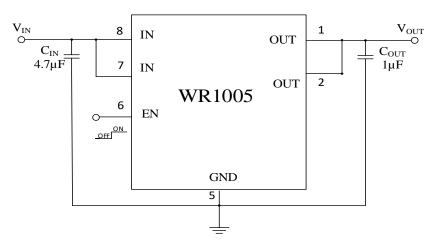
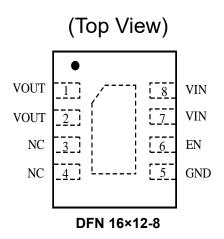


Figure 1. Typical Application Circuit

# **5. Pin Configuration**



# 6. Pin Description

PIN NUMBER	PIN NAME	I/O	PIN FUNCTION		
1			Regulated output voltage. A low equivalent series resistance (ESR) capacitor, typically 4.7µF, is required from OUT to		
2	V <sub>OUT</sub>	0	ground for stability. Place the output capacitor as close to the OUT and GND pins of the device as possible.		
3	NC		NC		
4	INC	-			
5	GND -		Common ground.		
6	EN	I	Enable input. Active High.		
7	V	.,	Input voltage supply. Bypass with a typical 4.7µF capacitor		
V <sub>IN</sub>		<b>!</b>	to GND. Place the input capacitor as close to the IN and GND pins of the device as possible.		



# 7. Absolute Maximum Ratings<sup>[1]</sup>

SYMBOL	PARAM	RATING	UNIT	
V <sub>IN</sub>	Input Voltage (V <sub>IN</sub> Pin)		-0.3 to 6.0	V
V <sub>EN</sub>	Input Voltaç	ge (EN Pin)	-0.3 to 6.0	V
V <sub>OUT</sub>	Output	-0.3 to 6.0	V	
P <sub>D</sub>	Power Dissipation <sup>[2][3]</sup> , $P_D @T_A = 25^{\circ}C$	DFN16×12-8	750	mW
R <sub>0JA</sub>	Thermal Resistance <sup>[2][3]</sup>	2	165	°C/W
Τ <sub>J</sub>	Junction Te	150	$^{\circ}$	
T <sub>SDR</sub>	Lead Temper	260	$^{\circ}$	
T <sub>STG</sub>	Storage Temperature Range		-55 to 150	$^{\circ}$
ESD	ESD Susceptibility HBM		±4000	V

**NOTE1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE2: Measured on 2cm x 2cm 2-layer FR4 PCB board, 1oz copper, no via holes on GND copper.

**NOTE3:** Power dissipation is calculated by  $P_{D(MAX)} = T_J - T_A / R_{\theta JA}$ .

# 8. Recommended Operating Conditions

SYMBOL	PARAMETER	RATING	UNIT
V <sub>IN</sub>	Input voltage range	2.5 to 5.5	V
V <sub>EN</sub>	EN Input voltage range	0 to 5.5	V
V <sub>OUT</sub>	Nominal output voltage range	1.0 to 3.3	V
I <sub>OUT</sub>	Output current	1	Α
C <sub>IN</sub>	Input capacitor	4.7	μF
Соит	Output capacitor	1	μF
T <sub>A</sub>	Operating temperature range	-40 to 85	${\mathbb C}$



### 9. Electrical Characteristics

 $(T_A=25~^{\circ}\text{C}\text{,}V_{IN}=V_{OUT}+1.0V\text{, }I_{OUT}=1\text{mA, }C_{IN}=4.7\mu\text{F,}C_{OUT}=1\mu\text{F,}unless otherwise noted})$ 

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP.	MAX	UNIT	
V <sub>OUT</sub>	Output Voltage Range	V <sub>IN</sub> =V <sub>OUT</sub> +1.0V	0.98 V <sub>оит</sub>		1.02 V <sub>оит</sub>	V	
	Dropout Voltage <sup>[4]</sup>	$V_{OUT}$ =3.3 $V$ , $I_{OUT}$ =1 $A$		130			
$V_{DO}$		V <sub>OUT</sub> =3.0V, I <sub>OUT</sub> =1A		130		mV	
		V <sub>OUT</sub> =1.8V, I <sub>OUT</sub> =1A		300			
I <sub>OUT</sub>	Output Current Limit	V <sub>IN</sub> =V <sub>OUT</sub> +0.5V	1000			mA	
I <sub>SHORT</sub>	Short Current Limit	V <sub>OUT</sub> =0V		160		mA	
LDR	Load Regulation <sup>[5]</sup>	V <sub>IN</sub> =V <sub>OUT</sub> +0.5V 1mA≤I <sub>OUT</sub> ≤1A		10		mV	
LNR	Line Regulation	V <sub>OUT</sub> +1V≤V <sub>IN</sub> ≤5.5V (V <sub>IN</sub> ≥UVLO)		5	10	mV	
IQ	Quiescent Current	V <sub>OUT</sub> =3.3V, I <sub>OUT</sub> =0mA		160		μA	
I <sub>SHDN</sub>	Standby Current	V <sub>EN</sub> =0V		1	3	μΑ	
I <sub>REV</sub>	Reverse Current	$V_{OUT}=V_{OSET}+1V$ , $V_{EN}=0V$ , $V_{IN}=0V$		4.5	10	μΑ	
I <sub>RUSH</sub>	Start from EN Current Limit	CC mode		500		mA	
PSRR	Power Supply Ripple Rejection	f=1kHz, Ripple=0.2Vp-p, V <sub>IN</sub> =V <sub>SET</sub> +1.0V, I <sub>OUT</sub> =10mA		60		dB	
e <sub>NO</sub>	Output noise voltage (V <sub>OUT</sub> =3V)	BW=10Hz to 100kHz,I <sub>OUT</sub> =0mA		50		/	
		BW=10Hz to 100kHz, I <sub>OUT</sub> =10mA		80		μV <sub>RMS</sub>	
$\frac{\Delta V_{OUT}}{\Delta T_A \times V_{OUT}}$	Output Voltage Temperature Coefficient	-40 °C≤T <sub>A</sub> ≤85 °C		90		ppm/°C	



SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>ENH</sub>	EN high voltage (enabled)	V <sub>IN</sub> =5.5V, I <sub>OUT</sub> =1mA	1.2			V
V <sub>ENL</sub>	EN low voltage (disabled)	V <sub>IN</sub> =5.5V, I <sub>OUT</sub> =1mA			0.4	V
T <sub>SD</sub>	Thermal shutdown threshold			165		°C
$\Delta T_{SD}$	Thermal shutdown hysteresis			30		°C
R <sub>DIS</sub>	Output Discharge resistance	V <sub>IN</sub> =4.0V, V <sub>EN</sub> =0V		60		Ω

**NOTE4:** The dropout voltage is defined as  $(V_{IN}-V_{OUT})$  when  $V_{OUT}$  is  $V_{OUT(NOM)}*98\%$ .

**NOTE5:** The Load regulation is measured by pulse test.

### 10. Typical Performance Characteristics

 $(T_A=-25 \, {}^{\circ}C,V_{IN}=V_{OUT}+1.0V, C_{IN}=4.7\mu F,C_{OUT}=1\mu F, unless otherwise noted)$ 

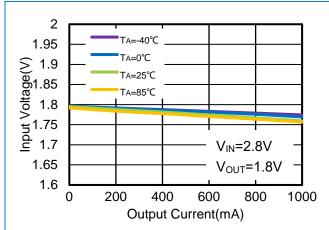


Figure 2.WR1005-18F18R Load Regulation vs .Output Current

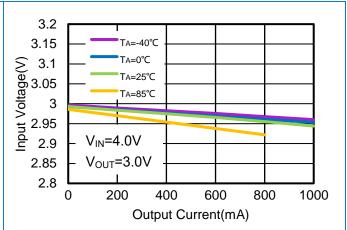


Figure 3.WR1005-30F18R Load Regulation vs .Output Current

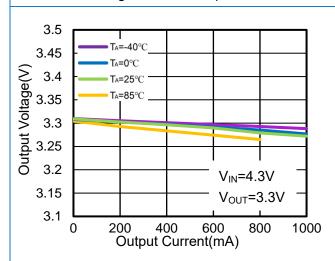


Figure 4.WR1005-33F18R

Load Regulation vs .Output Current

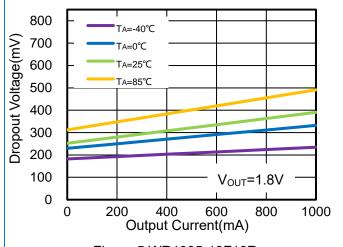
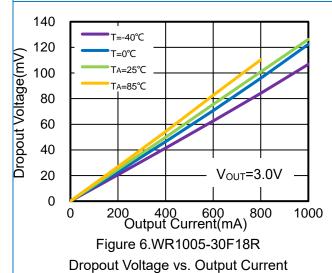
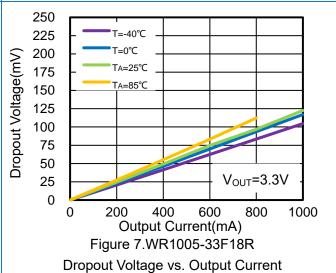
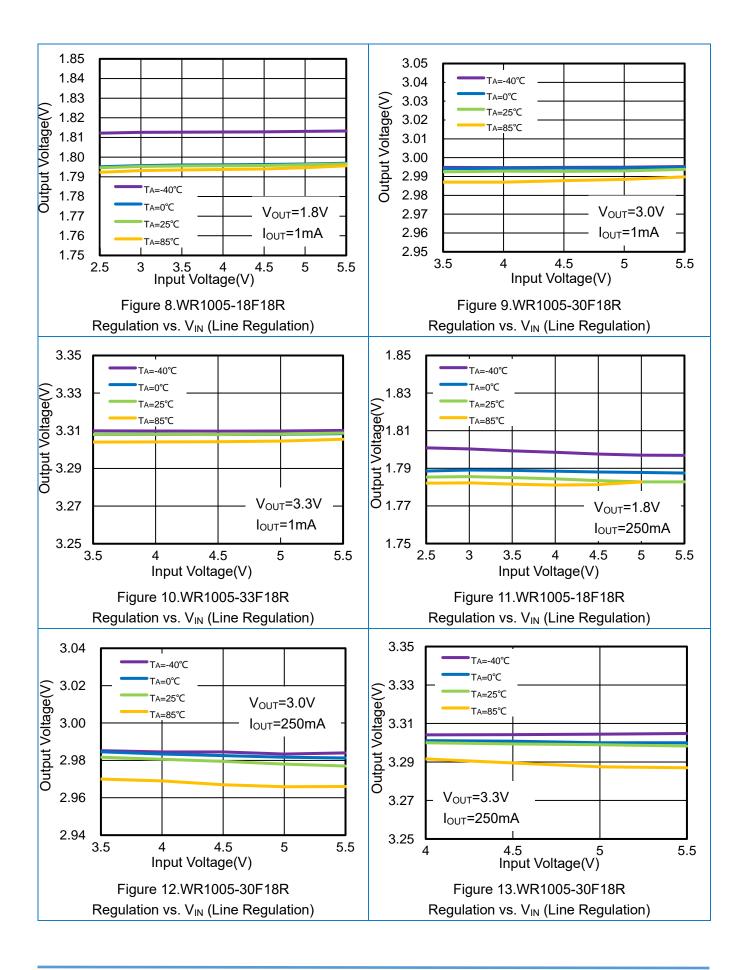


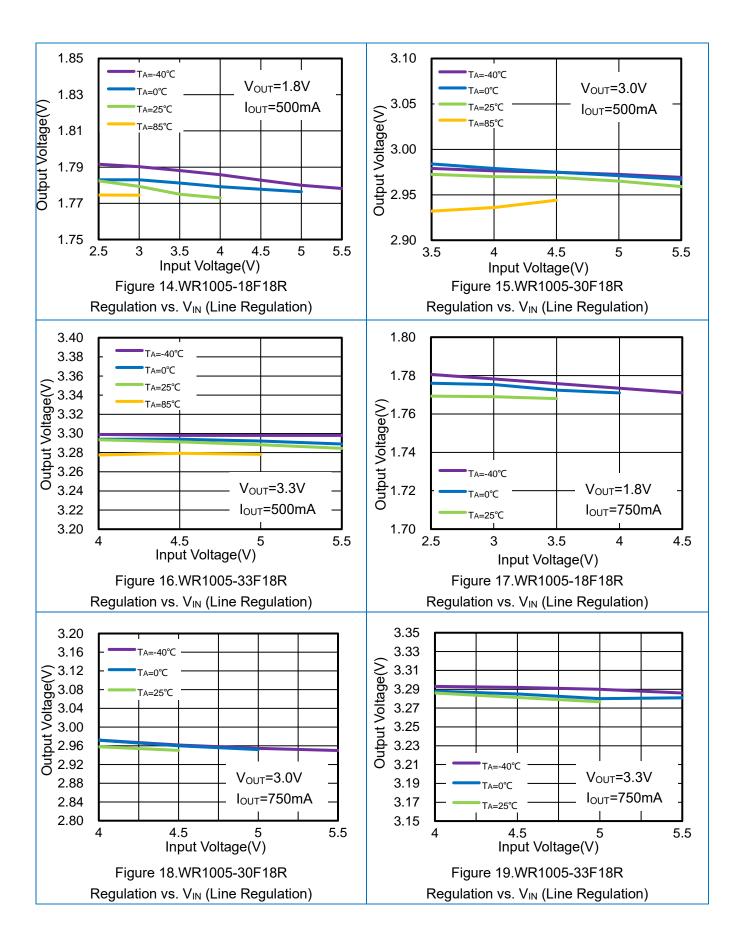
Figure 5.WR1005-18F18R
Dropout Voltage vs. Output Current

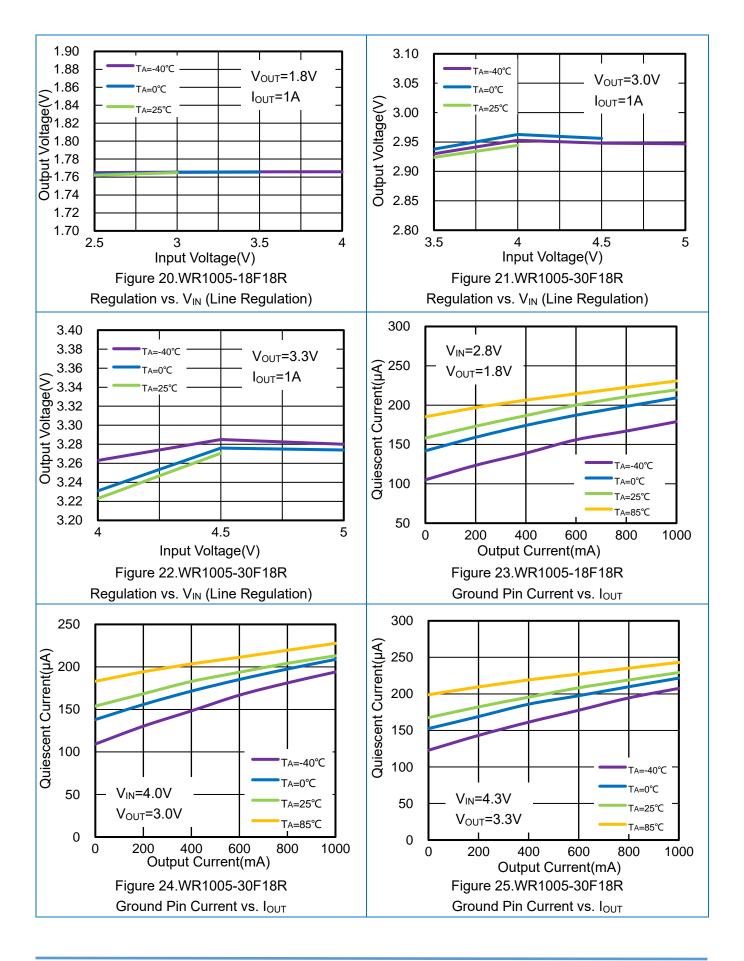




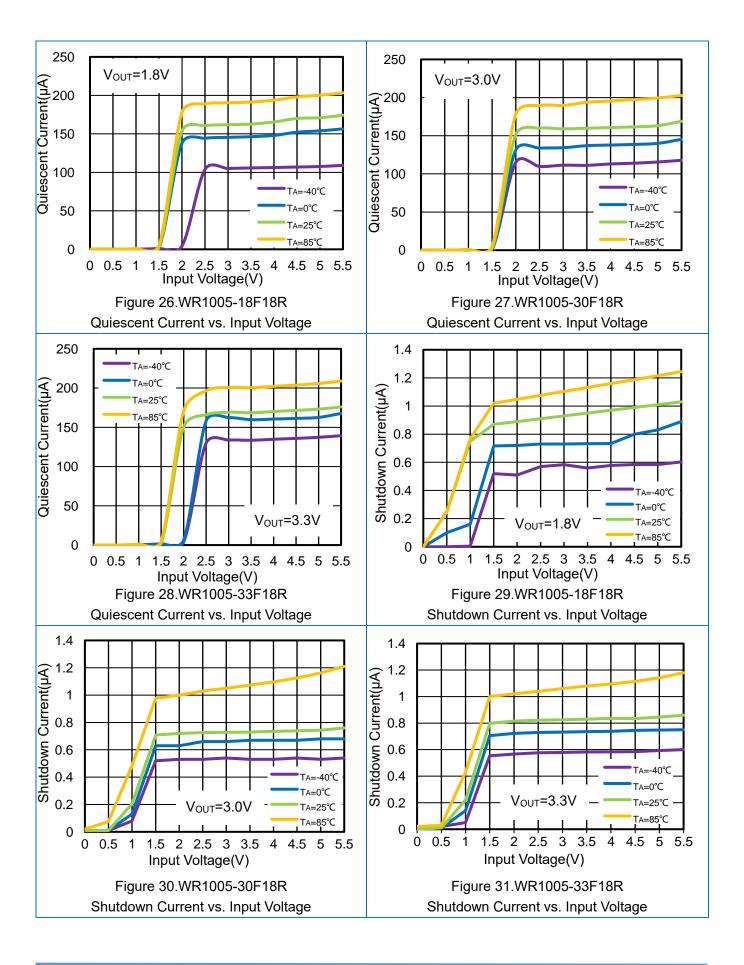


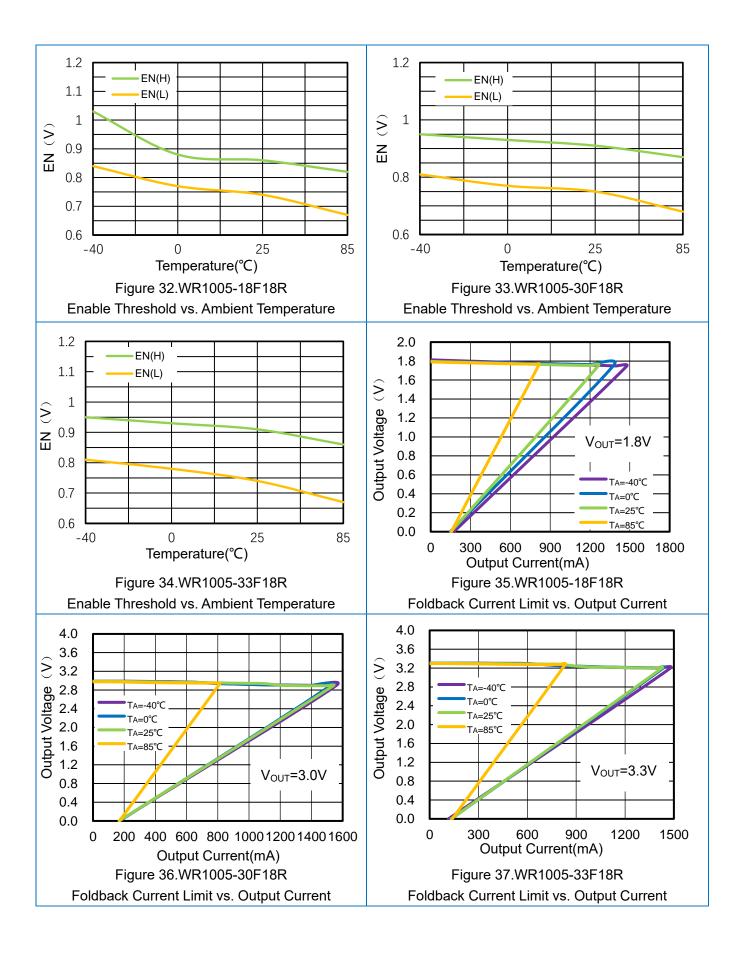


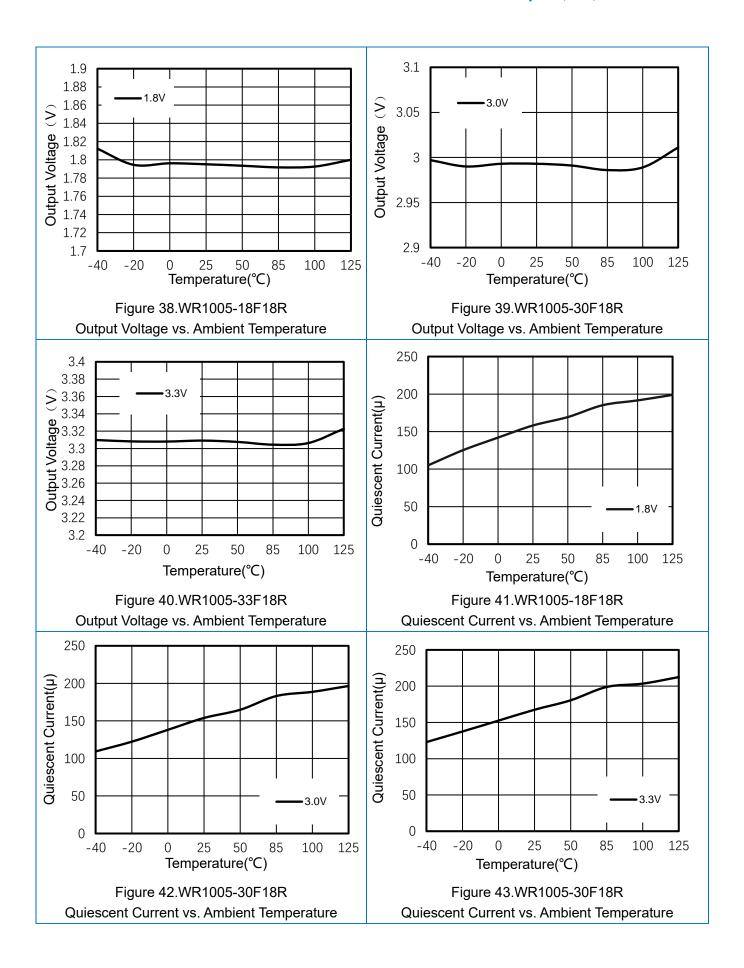




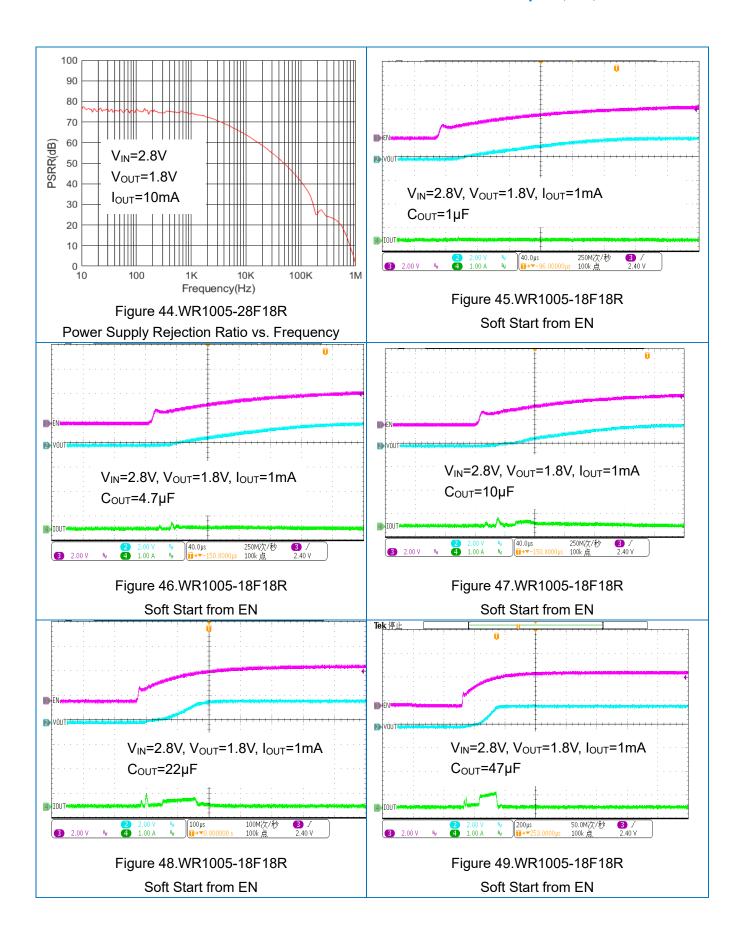




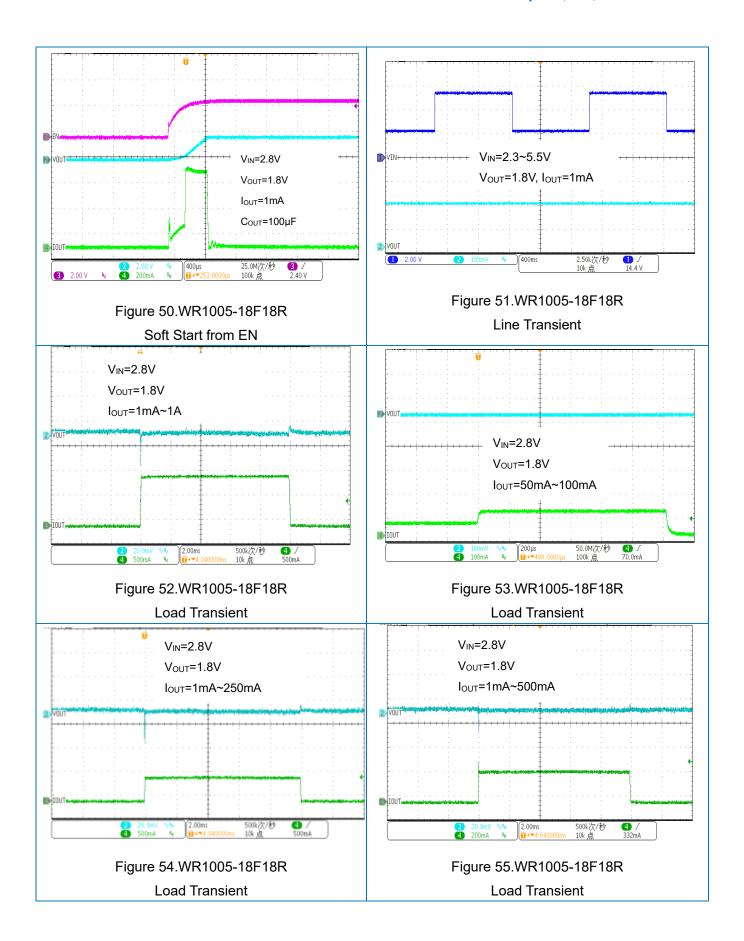




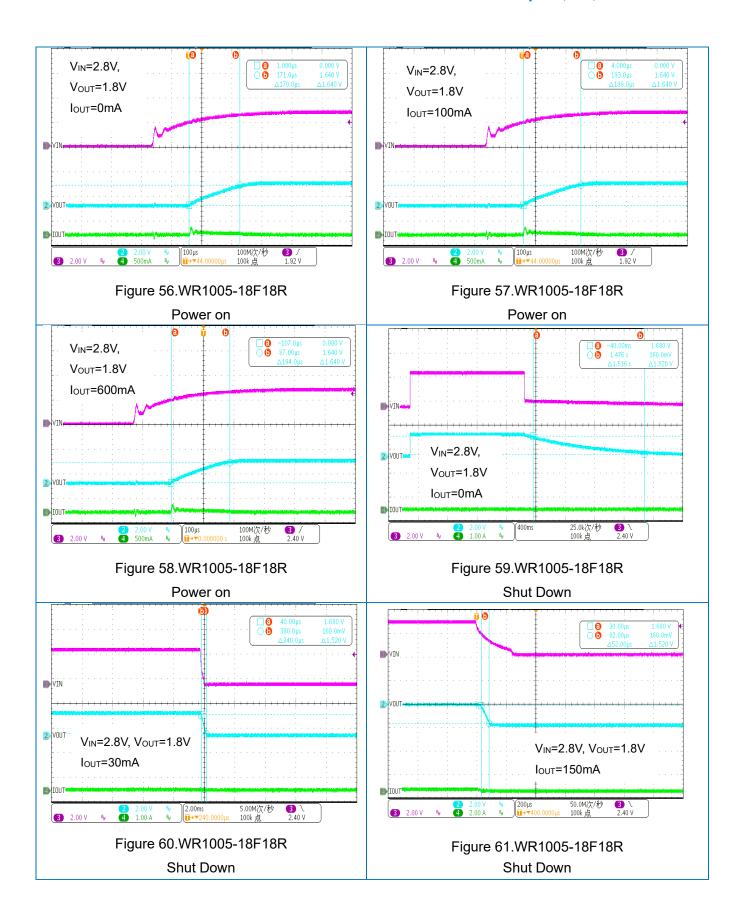










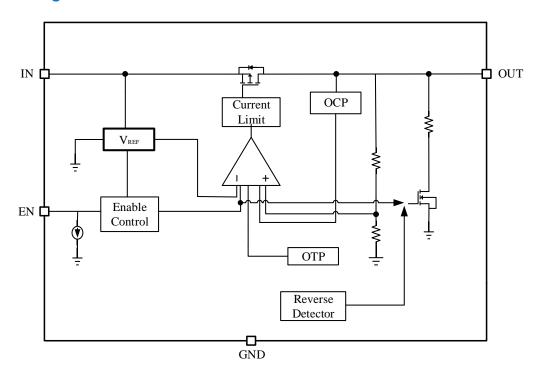


### 11. Function Description

#### 11.1 Overview

The WR1005 series are CMOS-based low-dropout, low-power linear regulators, offering 1A with low dropout voltage, high ripple rejection, high output accuracy and low supply current. The WR1005 series consist of an accurate voltage-reference block, an error amplifier, a voltage-setting resistor net, a PMOSFET pass device, a thermal-shutdown circuit, and a current limit circuit with short protection.

#### 11.2 Block Diagram



#### 11.3 Feature Description

#### 11.3.1 Output Voltage Accuracy

The WR1005 has an output voltage accuracy of 2%. Output voltage accuracy is defined as the maximum and minimum error in output voltage. This includes the errors introduced by internal reference, load regulation and line regulation differences over the full range of rated load and line operating conditions, taking into account differences between manufacturing lots.

#### 11.3.2 Enable (EN)

When the input voltage of the enable pin is higher than the high enable voltage threshold, the device outputs normally. When the input voltage of the enable pin is lower than the low input voltage threshold of the EN pin, the device outputs shutdown. If you do not need to control the output voltage independently, connect the enable pin to the input of the device.



#### 11.3.3 UVLO

When V<sub>IN</sub> voltage is lower than UVLO, even when EN is high, the device will not start.

#### 11.3.4 Dropout Voltage (V<sub>DO</sub>)

Dropout voltage is defined as the minimum of  $(V_{IN}-V_{OUT})$  at the rated maximum output current where  $V_{OUT}$  is the minimum of  $V_{OUT(NOM)}$ . When the input voltage is below  $V_{OUT(NOM)}$  plus  $V_{DO}$ , the output voltage varies with the input voltage.

For a CMOS regulator, the dropout voltage is determined by the drain-source on-state resistance ( $R_{DS (ON)}$ ) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. The  $R_{DS (ON)}$  is calculated by following equation.

$$R_{DS(ON)} = V_{DO}/I_{OUT}$$

#### 11.3.5 Power Supply Rejection Ratio (PSRR)

PSRR, which stands for Power Supply Rejection Ratio, represents the ratio of the two voltage gains obtained when the input and output power supplies are considered as two independent sources.

The basic calculation formula is

The units are in decibels (dB) and the logarithmic ratio is used.

The above equation shows that the output signal is influenced by the power supply in general, in addition to the circuit itself. PSRR is a quantity used to describe how the output signal is affected by the power supply; the larger the PSRR, the less the output signal is affected by the power supply.

As the level of integration continues to increase, the magnitude of supply current required is also increasing. End users want to extend battery life, i.e. they need very efficient DC/DC conversion processes, using more efficient switching regulators. However, switching regulators generate more—ripple in the power line than linear regulators.

The PSRR shows the ability of the LDO to suppress input voltage noise. For a clean, noise-free DC output voltage, use an LDO with a high PSRR.

Noise coupling from the input voltage to the internal reference voltage is the main cause of PSRR performance degradation. Using noise reduction capacitors at the input can effectively filter out noise and improve PSRR performance at low frequencies. The LDO can be used not only to regulate the voltage but also to provide an exceptionally clean DC supply for noise sensitive components.

The WR1005 is a high PSRR LDO that can be used not only for voltage regulation but also for noise cancellation in the power supply.



#### 11.3.6 Noise

LDO noise can be divided into two main categories: internal noise and external noise. Internal noise is the noise generated inside the electronics; external noise is the noise transmitted from outside the circuit to the circuit. The error amplifier determines the PSRR of the LDO and therefore its ability to suppress external noise at the input; internal noise is always present at the output of the LDO.

In practice, minimizing noise from the power supply is critical to system performance. In test and measurement systems, small fluctuations in power supply noise can alter the instantaneous measurement accuracy.

The WR1005 has a low noise reference, high PSRR to ensure that output noise is reduced during normal operation.

#### 11.3.7 Fold-back Current Limit (I<sub>LIM</sub>)

In LDO circuits, if an output short circuit or excessive load current occurs, the device may be burned out. Especially in the case of a short circuit, not only is there too much current flowing through the regulator, but the voltage across the source drain of the regulator is also at its maximum, which is likely to burn out the regulator and make the device inoperable. The current limiting circuit used in LDO is a constant current limiting circuit, where the maximum load current that the LDO can supply is limited to a set constant I<sub>LIM</sub>, and when an overload or short circuit occurs, the output current will be maintained at I<sub>LIM</sub>, and the output voltage will be reduced to I<sub>LIM</sub>R<sub>LOAD</sub>.

However, if the external overload or short circuit condition lasts for a long time, the continuous high current will increase the device temperature and increase the power consumption of the whole system. To improve this situation, a fold-back current limiting circuit can be used. In a fold-back current limiting circuit, both the output current and the output voltage are gradually reduced when the output current reaches the set maximum current I<sub>LIM</sub>. The output current is reduced to the set current threshold I<sub>SHORT</sub> and the output voltage is reduced to I<sub>SHORT</sub>R<sub>LOAD</sub>. The output current is clamped to a smaller value in the event of an overload or short circuit and the system power consumption is reduced and the device temperature does not rise significantly.

The fold-back current limiting circuit is essentially a constant current limiting circuit with an output voltage feedback loop, so that in the event of an overload or short circuit, the output current is gradually reduced due to the reduction in output voltage and eventually clamped at a smaller value.

#### 11.3.8 Thermal Protection

The WR1005 contains a thermal shutdown protection circuit that implements the required switching gate circuit function through a thermal switch integrated inside the chip. The output current is turned off when the heat in the LDO is too high. Thermal shutdown occurs when the thermal junction temperature (T<sub>J</sub>) of the energized crystal exceeds 165°C (typical). The thermal shutdown hysteresis ensures that the LDO resets (turns on) again when the temperature drops to 135°C (typical). The thermal time constant of the semiconductor chip is quite short, so when thermal shutdown is reached, the output turns on and off at a higher rate until the power dissipation is reduced.

The WR1005's internal protection circuitry is designed to prevent thermal overload conditions. This circuitry is not a substitute for a proper heat sink. Continuously putting the WR1005 into a thermal shutdown state will reduce the reliability of the device.



#### 11.3.9 Reverse Current Protection Circuit

The WR1005 include a Reverse Current Protection Circuit, which stop the reverse current from OUT pin to IN pin or GND pin when  $V_{OUT}$  becomes higher than  $V_{IN}$ .

When giving the OUT pin a constant voltage and decreasing the  $V_{IN}$  voltage, the  $V_{IN}$  voltage will become lower than  $V_{OUT}$ -Vrev\_det, the reverse current protection starts to function to stop the load current. By increasing the  $V_{IN}$  voltage higher than  $V_{OUT}$ -Vrev\_rel, the protection mode will be released to let the load current to flow. When  $V_{IN}$  voltage is between  $V_{OUT}$  and  $V_{IN}$  and  $V_{IN}$  voltage is between  $V_{OUT}$  and  $V_{IN}$  and  $V_{IN}$  pin and  $V_{IN}$ 

#### 11.4 Device Functional Modes

The device has three modes: normal, dropout, and disabled modes of operation.

The operating conditions of each mode are listed in the table below.

#### **CONDITIONS FUNCTIONAL MODE** VIN VEN $T_{J}$ lout $5.5V > V_{IN} > V_{OUT(nom)} + V_{DO}$ $V_{EN} > V_{ENH}$ Normal $I_{OUT} < I_{LIM}$ $T_{J} < T_{SD}$ $V_{IN} < V_{OUT(nom)} + V_{DO}$ $V_{EN} > V_{ENH}$ Dropout $I_{OUT} < I_{LIM}$ $T_{J} < T_{SD}$ $V_{EN} < V_{ENL}$ $V_{IN} < V_{U\underline{VLO}}$ Disabled $T_J > T_{SD}$

#### Operating conditions of each mode

#### 11.4.1 Normal Mode

Normal operating mode requires that both of the following conditions are met.

- 1. The input voltage is greater than the rated output voltage plus the differential voltage ( $V_{OUT(NOM)} + V_{DO}$ ) and is less than 5.5V.
- 2. The enable voltage has previously exceeded the enable rise threshold voltage and has not fallen below the enable fall threshold.
- 3. The output current is less than the current limit ( $I_{OUT} < I_{LIM}$ ).
- 4. The device junction temperature is less than the thermal shutdown temperature ( $T_J < T_{SD}$ ).



#### 11.4.2 Dropout Mode

If the input voltage is below the rated output voltage plus a specified dropout voltage, but all other conditions are met for normal operation, the device operates in the dropout state and the output voltage tracks the input voltage. Because the transient performance of the device is significantly reduced through the device being in the triode state, the output current is no longer controlled. Line or load transients during power down can result in large output voltage deviations.

#### 11.4.3 Disabled

The WR1005 can be turned off by forcing the enable pin low, typically with an enable voltage below 0.4V, at which point the pass device is turned off, internal circuits are shutdown, and the output voltage is actively discharged to ground through an internal resistor from output to ground.

### 12. Application and Implementation

**NOTE:** The information in the Applications section below is not part of WAY-ON's product specifications and WAY-ON does not guarantee its accuracy or completeness. The customer is responsible for determining the suitability of the component for its intended use and should verify and test its design implementation to confirm system functionality.

### 12.1 Application Information

The WR1005 is a linear voltage regulator with an input voltage of 2.5 V to 5.5 V and an output voltage of 1.0 V to 3.3 V. The accuracy is 2% for output voltages . The maximum output current is 1A. The efficiency of a linear voltage regulator is determined by the ratio of the output voltage to the input voltage, so in order to achieve high efficiency, the differential voltage ( $V_{\text{IN}}-V_{\text{OUT}}$ ) must be as small as possible. This section discusses how best to use this device in practical applications.

#### 12.1.1 Start-Up

#### 12.1.1.1 Inrush Current Limit

Constant slope circuit is included in the WR1005 to prevent the overshoot of the output voltage. If inrush current increases due to the large capacitance of  $C_{OUT}$ , the operation mode will be shift from Constant Slope (CS) mode to Constant Current (CC) mode. The CC mode maintains a constant inrush current. In the CC mode,  $t_{RISE}$  of  $V_{OUT}$  varies with the size of  $C_{OUT}$  and the load current.

#### 12.1.1.2 Automatic Discharge

The WR1005 has an internal pull-down MOSFET that connects a discharge resistor from V<sub>OUT</sub> to ground to actively release the output voltage when the device is disabled.

#### 12.1.2 Capacitor Recommendation

The WR1005 uses ceramic capacitors with low equivalent series resistance (ESR) at the  $V_{IN}$  and  $V_{OUT}$  pins to increase its stability. Multilayer ceramic capacitors are recommended. These capacitors also have limitations, and ceramic capacitors with X7R-, X5R-, and COG-rated dielectric materials have relatively good capacitance stability at different temperatures. WR1005 is designed to use ceramic capacitors of 4.7  $\mu$ F or larger at the input and output. Place  $C_{IN}$  and  $C_{OUT}$  as close to the IN and OUT pins as possible to minimize trace inductance from the capacitor to the device.



Increasing the input capacitance can reduce the transient input drop during start-up and load current. If the  $C_{\text{OUT}}$  produces high Q peak effects during transients, using only very large ceramic input capacitors can cause unwanted ringing at the OUT side, which requires well-designed short interconnects to the upstream supply to reduce ringing. Using a tantalum capacitor with an ESR of several hundred milliohms in parallel with the ceramic input capacitor can avoid unwanted ringing. The load step transient response is the output voltage response of the LDO to a step change in load current. A larger output capacitor reduces any voltage dips or spikes that occur during the load step, but at the same time the control loop bandwidth is reduced, which slows the response time.

Because, the LDO cannot consume charge, the control loop must close through the FET when the output load is removed or greatly reduced and wait for any excess charge to be depleted.

#### 12.1.3 Power Dissipation(P<sub>D</sub>)

The reliability of the circuit requires reasonable consideration of the power dissipation of the device, the location of the circuit on the PCB, and the proper sizing of the thermal plane. The regulator should be surrounded by no other heat generating devices as much as possible. The power dissipation of the regulator depends on the input and output voltage difference and the load conditions.

P<sub>D</sub> can be calculated using the following equation:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$$

Using the proper input voltage minimizes the power dissipation, resulting in greater efficiency. To obtain the lowest power dissipation, use the minimum input voltage required for normal output voltage.

The maximum power dissipation determines the maximum allowable ambient temperature ( $T_A$ ) of the device. Power dissipation and junction temperature are typically related to the junction-ambient thermal resistance ( $R_{\theta JA}$ ) and ambient air temperature ( $T_A$ ) of the PCB and package and are calculated as follows

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

The thermal resistance  $(R_{\theta JA})$  depends primarily on the thermal dispersion capability of the PCB design. The total copper area, copper weight, and the location of the plane all affect the thermal dispersion capability, and the PCB and copper laydown area can only be used as a relative measure of the package's thermal performance.

### 13. Power Supply Recommendations

The WR1005 has a  $V_{IN}$  range of between 2.5 V and 5.5 V and an input capacitance of 4.7 $\mu$ F. The input voltage should have some redundancy to ensure a stable output voltage when the load fluctuates. If the input supply is noisy, additional input capacitors can be used to improve the noise performance of the output.

### 14. Evaluation Modules

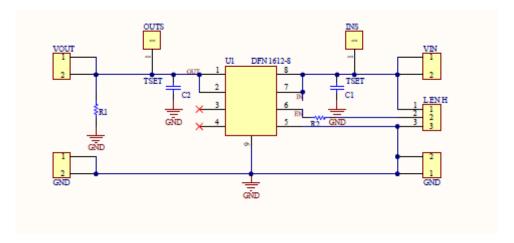
Evaluation Modules (EVMs) are available to help evaluate initial circuit performance. We have evaluation modules for different packages, you can contact us to get the evaluation module or schematic.

The module names are listed in the following table.

NAME	PACKAGE	EVALUATION MODULE
WR1005	DFN16×12-8	WAYON LDO EVM V1.1-DFN1612-8

#### 14.1 Schematic

This section discusses the application of the WR1005 in the circuit. The following figure shows the schematic of the application circuit.



#### 14.2 Layout

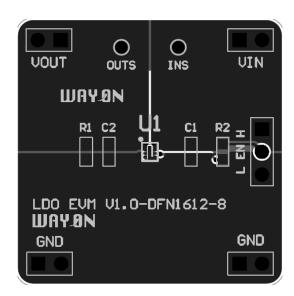
#### **Layout Guidelines**

The principle of LDO design is to place all components on the same side of the board and connect them as close as possible to their respective LDO pins. A  $1.0\mu\text{F}$  input capacitor ( $C_{\text{IN}}$ ) is recommended to IN to minimize the effect of resistance and inductance between the source and the LDO input. A  $1.0\mu\text{F}$  or smaller output capacitor ( $C_{\text{OUT}}$ ) is recommended to OUT. Connect the ground sides of  $C_{\text{IN}}$  and  $C_{\text{OUT}}$  with LDO ground pins as close as possible through a wide copper surface. Through-holes and long wires may seriously affect system performance and is not recommended.



To improve thermal performance, an array of thermal vias is used to connect the thermal pad to the ground plane. A larger ground plane improves the thermal performance of the device and reduces the operating temperature of the device.

### **Layout Example**





### 15. Naming Conventions

#### WR AA BB-CC DDD E

**WR:** WAYON Regulator; **AA:** 10-Output Current,1A;

**BB:**Serial number; **CC:**Output Voltage;

DDD: Package - F18: DFN16×12-8;

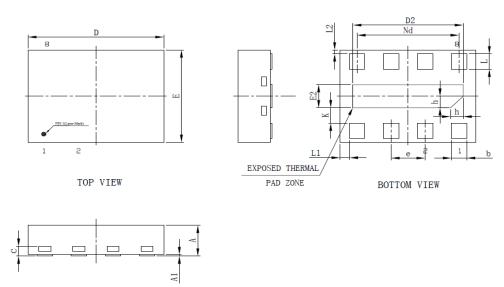
E: R-Reel & T-tube;

### 16. Electrostatic discharge warning

ESD can cause irreversible damage to integrated circuits, ranging from minor performance degradation to device failure. Precision ICs are more susceptible to damage because very minor parameter changes can cause the device to be out of compliance with its published specifications. WAY-ON recommends that all ICs be handled with proper precautions. Failure to follow proper handling practices and installation procedures may damage the IC.

# 17. Package Information

### DFN16×12-8



SYMBOL	DIMENSIONS IN MILLIMETERS				
STWIDUL	MIN	NOM	MAX		
Α	0.35	-	0.40		
<b>A</b> 1	0	0.02	0.05		
b	0.13	0.18	0.23		
С		0.127REF			
D	1.55	1.55 1.60 1.65			
D2	1.25 1.30 1.35				
е		0.40BSC			
Nd		1.20BSC			
E	1.15	1.20	1.25		
E2	0.25	0.25 0.30 0.3			
L	0.15 0.20 0.25				
L1	0.06 0.11 0.16				
L2	0.05REF				
h	0.10	0.15	0.20		
k	0.15	0.20	0.25		

### 18. Ordering Information

PART NUMBER	OUTPUT VOLTAGE	PACKAGE	PACKING QUANTITY	MARKING*
WR1005-18F18R	1.8V	DFN-8	3k/Reel	005 18
WR1005-185F18R	1.85V	DFN-8	3k/Reel	005 185
WR1005-28F18R	2.8V	DFN-8	3k/Reel	005 28
WR1005-30F18R	3.0V	DFN-8	3k/Reel	005 30
WR1005-33F18R	3.3V	DFN-8	3k/Reel	005 33

<sup>\*</sup> XXXX is variable.

#### **Contact Information**

No.1001, Shiwan(7) Road, Pudong District, Shanghai, P.R.China.201207 Tel: 86-21-50310888 Fax: 86-21-50757680 Email: market@way-on.com

WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

**■ RYDN**® is registered trademark of Wayon Corporation.

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.

Users should verify actual device performance in their specific applications.



#### **Product Specification Statement**

- The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.
- The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.
- WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.
- Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.
- The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.
- Users should also comply with relevant laws, regulations, policies, and standards when using the product specification. Users are responsible for the risks and liabilities arising from the use of the product specification and must ensure that it is not used for illegal purposes. Additionally, users should respect the intellectual property rights related to the product specification and refrain from infringing upon any third-party legal rights. WAYON shall assume no responsibility for any disputes or controversies arising from the above-mentioned issues in any form.